

SANYO Semiconductors DATA SHEET

PNP Epitaxial Planar Silicon Transistor

CPH6005 — Video Output Driver, High-Frequency **Amplifier Applications**

Features

- High fT (fT=1.5GHz typ).
- · Large current (IC= -300mA).
- · Adoption of FBET process.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	VEBO		-3	V
Collector Current	IC		-300	mA
Collector Current (Pulse)	ICP		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² X0.8mm)	1.0	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =-20V, I _E =0A			-0.1	μΑ
Emitter Cutoff Current	IEBO	VEB=-2V, IC=0A			-1.0	μΑ
DC Current Gain	hFE1	V _{CE} =-5V, I _C =-50mA	15		100	
	hFE2	V _{CE} =-5V, I _C =-300mA	5			
Gain-Bandwidth Product	fŢ	VCE=-5V, IC=-100mA		1.5		GHz
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		4.9		pF
Reverse Transfer Capacitance	Cre	V _{CB} =-10V, f=1MHz		4.4		pF

Marking: GE Continued on next page.

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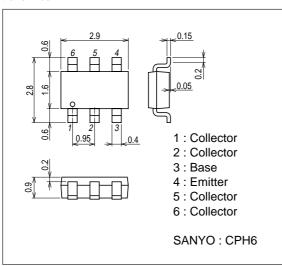
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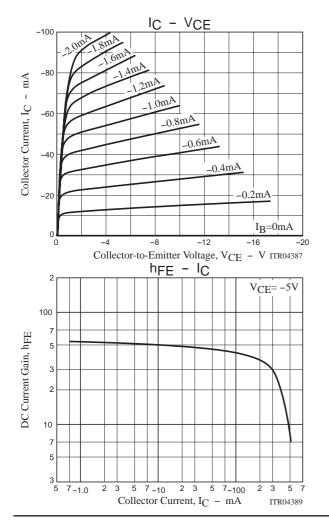
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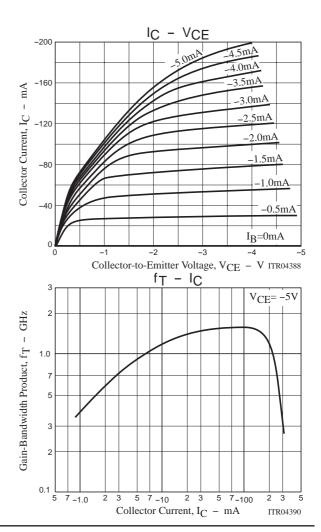
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oille
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=-100mA, IB=-10mA		-0.4	-1.0	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=-100mA, IB=-10mA		-0.9	-1.2	V

Package Dimensions

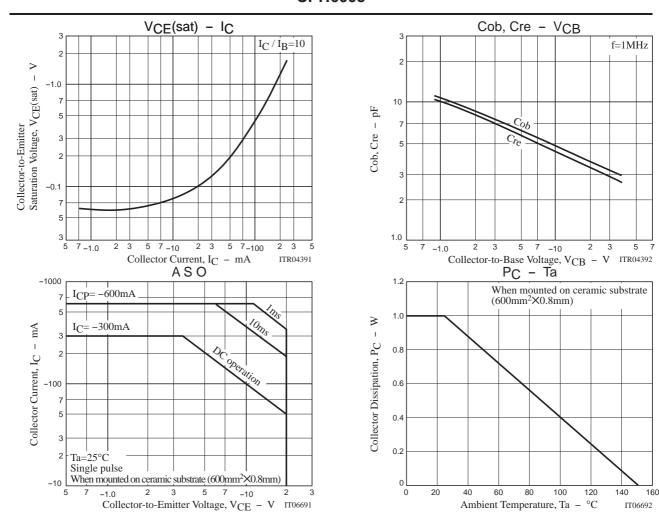
unit : mm (typ) 7018A-002







CPH6005



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